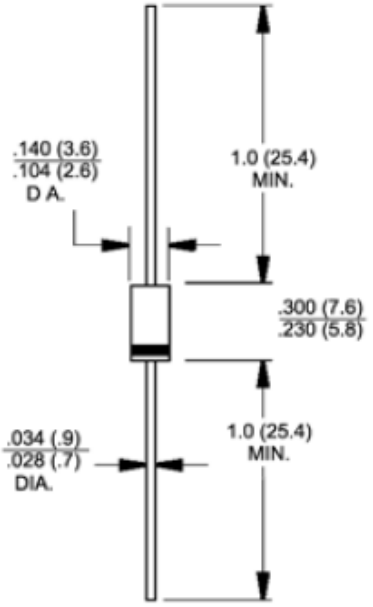
Transient Voltage Suppressors

FEATURES

- Peak Pulse Power 500W
- Stand Off Voltage 5.0 to 180V
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated junction
- Excellent clamping capability
- Low incremental surge resistance
- Very fast response time
- 500W peak pulse power surge capability with a 10/100us waveform, repetition rate (duty cycle): 0.01%
- High temperature soldering guaranteed: 265oC/10 seconds 0.375" (9.5mm) lead length, 5lbs. (2.3kg) tension



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC DO-204AC(DO-15) molded plastic body over passivated junction
- Terminals: Solder plated axial leads, solder-able per MIL-STD-750, Method 2026
- Polarity: For unidirectional types the color band denotes the cathode, which is positive with respect to the anode under normal TVS operation
- Mounting Position: Any
- Weight: 0.015oz., 0.4g

Pb-free; RoHS-compliant

MAXIMUM RATINGS (T_A=25℃ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak pulse power dissipation with a 10/1000us waveform (1) (Fig. 1)	P_{PPM}	500 (Min.)	W
Peak pulse current with a 10/1000us waveform (1)	I_{PPM}	See Next Table	A
Steady state power dissipation at TA =75℃ lead lengths, 0.375" (9.5mm) (2)	$P_{M(AV)}$	3.0	W
Peak forward surge current, 10ms single half sine-wave unidirectional only	I_{FSM}	70	A
Maximum instantaneous forward voltage at 35A for unidirectional only	V_F	3.5	Volts
Operating junction and storage temperature range	$T_{J, TSTG}$	-55 to +175	℃

NOTE: 1. Non-repetitive current pulse, per Fig. 3 and derated above TA=25℃ per Fig. 2.
2. Mounted on copper pad area of 1.6 x 1.6" (40 x 40mm) per Fig. 5.
3. 8.3ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum.

ELECTRICAL CHARACTERISTICS (T_A = 25°C , unless otherwise specified.)

Device type	Breakdown voltage $V_{(BR)}$ (Volts) (1) Min.	Breakdown voltage $V_{(BR)}$ (Volts) (1) Max.	Test current at I_T (mA)	Stand-off voltage V_{WM} (Volts)	Maximum reverse leakage at V_{WM} I_D (3) (uA)	Maximum peak pulse surge current I_{PPM} (2) (A)	Maximum clamping voltage at I_{PPM} V_C (Volts)	Maximum temperature coefficient of $V_{(BR)}$ (mV / °C)
SA5.0	6.40	7.30	10	5.0	600	52.1	9.6	5.0
SA5.0A (4)	6.40	7.07	10	5.0	600	54.3	9.2	5.0
SA6.0	6.67	8.15	10	6.0	600	43.9	11.4	5.0
SA6.0A	6.67	7.37	10	6.0	600	48.5	10.3	5.0
SA6.5	7.22	8.82	10	6.5	400	40.7	12.3	5.0
SA6.5A	7.22	7.98	10	6.5	400	44.7	11.2	5.0
SA7.0	7.78	9.51	10	7.0	150	37.6	13.3	6.0
SA7.0A	7.78	8.60	10	7.0	150	41.7	12.0	6.0
SA7.5	8.33	10.2	1.0	7.5	50	35.0	14.3	7.0
SA7.5A	8.33	9.21	1.0	7.5	50	38.8	12.9	7.0
SA8.0	8.89	10.9	1.0	8.0	25	33.3	15.0	7.0
SA8.0A	8.89	9.83	1.0	8.0	25	36.8	13.6	7.0
SA8.5	9.44	11.5	1.0	8.5	10	31.4	15.9	8.0
SA8.5A	9.44	10.4	1.0	8.5	10	34.7	14.4	8.0
SA9.0	10.0	12.2	1.0	9.0	5.0	29.6	16.9	9.0
SA9.0A	10.0	11.1	1.0	9.0	5.0	32.5	15.4	9.0
SA10	11.1	13.6	1.0	10.0	1.0	26.6	18.8	10.0
SA10A	11.1	12.3	1.0	10.0	1.0	29.4	17.0	10.0
SA11	12.2	14.9	1.0	11.0	1.0	24.9	20.1	11.0
SA11A	12.2	13.5	1.0	11.0	1.0	27.5	18.2	11.0
SA12	13.3	16.3	1.0	12.0	1.0	22.7	22.0	12.0
SA12A	13.3	14.7	1.0	12.0	1.0	25.1	19.9	12.0
SA13	14.4	17.6	1.0	13.0	1.0	21.0	23.8	13.0
SA13A	14.4	15.9	1.0	13.0	1.0	23.3	21.5	13.0
SA14	15.6	19.1	1.0	14.0	1.0	19.4	25.8	14.0
SA14A	15.6	17.2	1.0	14.0	1.0	21.6	23.2	14.0
SA15	16.7	20.4	1.0	15.0	1.0	18.6	26.9	16.0
SA15A	16.7	18.5	1.0	15.0	1.0	20.5	24.4	16.0
SA16	17.8	21.8	1.0	16.0	1.0	17.4	28.8	19.0
SA16A	17.8	19.7	1.0	16.0	1.0	19.2	26.0	17.0
SA17	18.9	23.1	1.0	17.0	1.0	16.4	30.5	20.0
SA17A	18.9	20.9	1.0	17.0	1.0	18.1	27.6	19.0
SA18	20.0	24.4	1.0	18.0	1.0	15.5	32.2	21.0
SA18A	20.0	22.1	1.0	18.0	1.0	17.1	29.2	20.0
SA20	22.2	27.1	1.0	20.0	1.0	14.0	35.8	25.0
SA20A	22.2	24.5	1.0	20.0	1.0	15.4	32.4	23.0
SA22	24.4	29.8	1.0	22.0	1.0	13.1	39.4	28.0
SA22A	24.4	26.9	1.0	22.0	1.0	14.1	35.5	25.0
SA24	26.7	32.6	1.0	24.0	1.0	11.6	43.0	31.0
SA24A	26.7	29.5	1.0	24.0	1.0	12.9	38.9	28.0
SA26	28.9	35.3	1.0	26.0	1.0	10.7	46.6	31.0
SA26A	28.9	31.9	1.0	26.0	1.0	11.9	42.1	30.0
SA28	31.1	38.0	1.0	28.0	1.0	10.0	50.1	35.0
SA28A	31.1	34.4	1.0	28.0	1.0	11.0	45.4	31.0
SA30	33.3	40.7	1.0	30.0	1.0	9.3	53.5	39.0
SA30A	33.3	36.8	1.0	30.0	1.0	10	48.4	36.0

ELECTRICAL CHARACTERISTICS (T_A = 25°C , unless otherwise specified.)

Device type	Breakdown voltage $V_{(BR)}$ (Volts) (1) Min.	Max.	Test current at I_T (mA)	Stand-off voltage V_{WM} (Volts)	Maximum reverse leakage at V_{WM} I_D (3) (uA)	Maximum peak pulse surge current I_{PPM} (2) (A)	Maximum clamping voltage at I_{PPM} V_C (Volts)	Maximum temperature coefficient of $V_{(BR)}$ (mV / °C)
SA5.0	6.40	7.30	10	5.0	600	52.1	9.6	5.0
SA5.0A (4)	6.40	7.07	10	5.0	600	54.3	9.2	5.0
SA6.0	6.67	8.15	10	6.0	600	43.9	11.4	5.0
SA6.0A	6.67	7.37	10	6.0	600	48.5	10.3	5.0
SA6.5	7.22	8.82	10	6.5	400	40.7	12.3	5.0
SA6.5A	7.22	7.98	10	6.5	400	44.7	11.2	5.0
SA7.0	7.78	9.51	10	7.0	150	37.6	13.3	6.0
SA7.0A	7.78	8.60	10	7.0	150	41.7	12.0	6.0
SA7.5	8.33	10.2	1.0	7.5	50	35.0	14.3	7.0
SA7.5A	8.33	9.21	1.0	7.5	50	38.8	12.9	7.0
SA8.0	8.89	10.9	1.0	8.0	25	33.3	15.0	7.0
SA8.0A	8.89	9.83	1.0	8.0	25	36.8	13.6	7.0
SA8.5	9.44	11.5	1.0	8.5	10	31.4	15.9	8.0
SA8.5A	9.44	10.4	1.0	8.5	10	34.7	14.4	8.0
SA9.0	10.0	12.2	1.0	9.0	5.0	29.6	16.9	9.0
SA9.0A	10.0	11.1	1.0	9.0	5.0	32.5	15.4	9.0
SA10	11.1	13.6	1.0	10.0	1.0	26.6	18.8	10.0
SA10A	11.1	12.3	1.0	10.0	1.0	29.4	17.0	10.0
SA11	12.2	14.9	1.0	11.0	1.0	24.9	20.1	11.0
SA11A	12.2	13.5	1.0	11.0	1.0	27.5	18.2	11.0
SA12	13.3	16.3	1.0	12.0	1.0	22.7	22.0	12.0
SA12A	13.3	14.7	1.0	12.0	1.0	25.1	19.9	12.0
SA13	14.4	17.6	1.0	13.0	1.0	21.0	23.8	13.0
SA13A	14.4	15.9	1.0	13.0	1.0	23.3	21.5	13.0
SA14	15.6	19.1	1.0	14.0	1.0	19.4	25.8	14.0
SA14A	15.6	17.2	1.0	14.0	1.0	21.6	23.2	14.0
SA15	16.7	20.4	1.0	15.0	1.0	18.6	26.9	16.0
SA15A	16.7	18.5	1.0	15.0	1.0	20.5	24.4	16.0
SA16	17.8	21.8	1.0	16.0	1.0	17.4	28.8	19.0
SA16A	17.8	19.7	1.0	16.0	1.0	19.2	26.0	17.0
SA17	18.9	23.1	1.0	17.0	1.0	16.4	30.5	20.0
SA17A	18.9	20.9	1.0	17.0	1.0	18.1	27.6	19.0
SA18	20.0	24.4	1.0	18.0	1.0	15.5	32.2	21.0
SA18A	20.0	22.1	1.0	18.0	1.0	17.1	29.2	20.0
SA20	22.2	27.1	1.0	20.0	1.0	14.0	35.8	25.0
SA20A	22.2	24.5	1.0	20.0	1.0	15.4	32.4	23.0
SA22	24.4	29.8	1.0	22.0	1.0	13.1	39.4	28.0
SA22A	24.4	26.9	1.0	22.0	1.0	14.1	35.5	25.0
SA24	26.7	32.6	1.0	24.0	1.0	11.6	43.0	31.0
SA24A	26.7	29.5	1.0	24.0	1.0	12.9	38.9	28.0
SA26	28.9	35.3	1.0	26.0	1.0	10.7	46.6	31.0
SA26A	28.9	31.9	1.0	26.0	1.0	11.9	42.1	30.0
SA28	31.1	38.0	1.0	28.0	1.0	10.0	50.1	35.0
SA28A	31.1	34.4	1.0	28.0	1.0	11.0	45.4	31.0
SA30	33.3	40.7	1.0	30.0	1.0	9.3	53.5	39.0
SA30A	33.3	36.8	1.0	30.0	1.0	10	48.4	36.0

NOTE:
1. $V_{(BR)}$ measured after IT applied for 300us. IT=square wave pulse or equivalent
2. Surge current waveform per Fig. 3 and derate per Fig. 2
3. For bidirectional types with VWM of 10 Volts and less, the ID limit is doubled
4. For the bidirectional SA5.0CA, the maximum VBR is 7.25V
5. All terms and symbols are consistent with ANSI/IEEE C62.35
6. For parts without A, the VBR is +10%

RATINGS AND CHARACTERISTIC CURVES (T_A = 25°C , unless otherwise specified.)

Fig. 1 – Peak Pulse Power Rating Curve

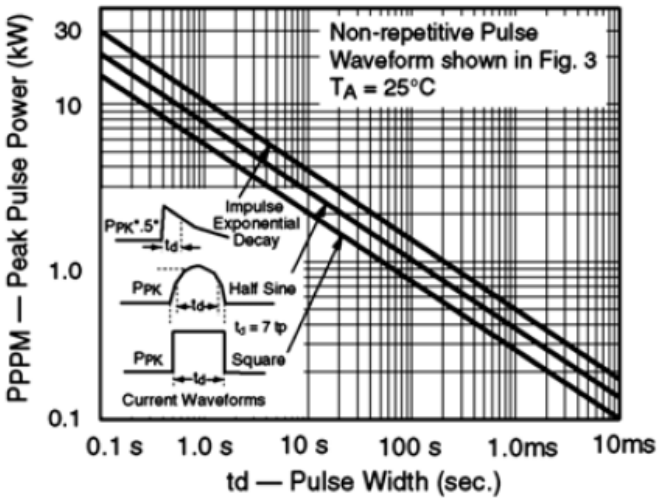


Fig. 2 – Pulse Derating Curve

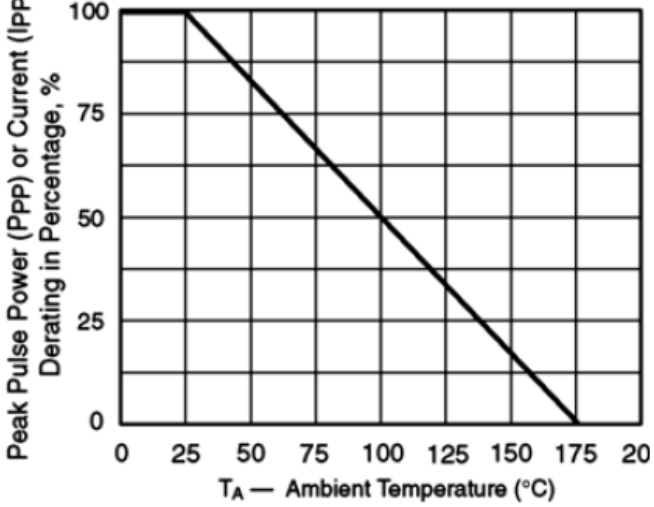


Fig. 3 – Pulse Waveform

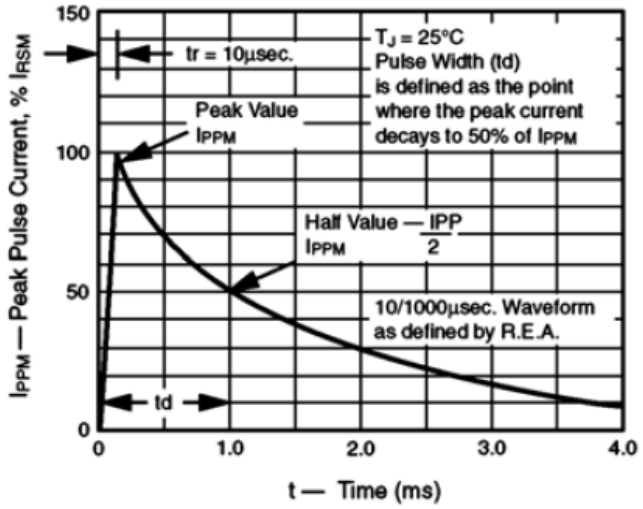


Fig. 4 - Maximum Non-Repetitive Forward Surge Current Uni-Directional Only

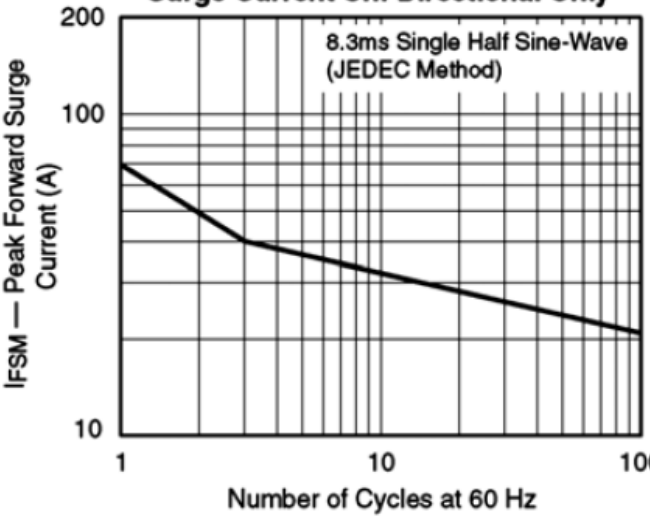


Fig. 5 – Steady State Power Derating Curve

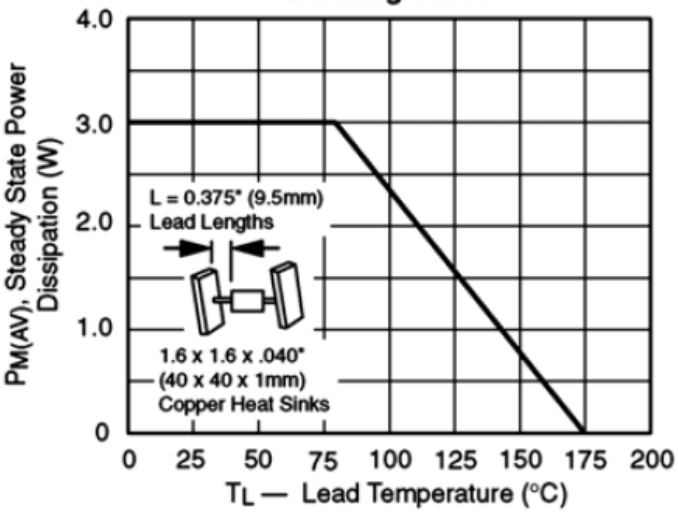
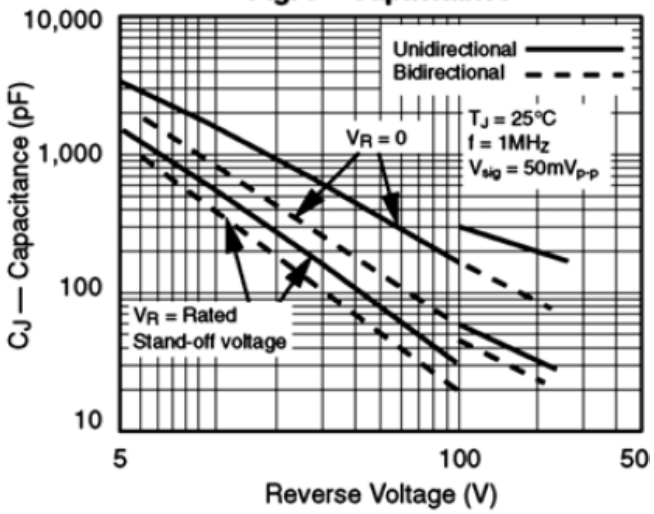


Fig. 6 – Capacitance



RATINGS AND CHARACTERISTIC CURVES (T_A = 25°C , unless otherwise specified.)

Fig. 7 – Incremental Clamping Voltage Curve Unidirectional

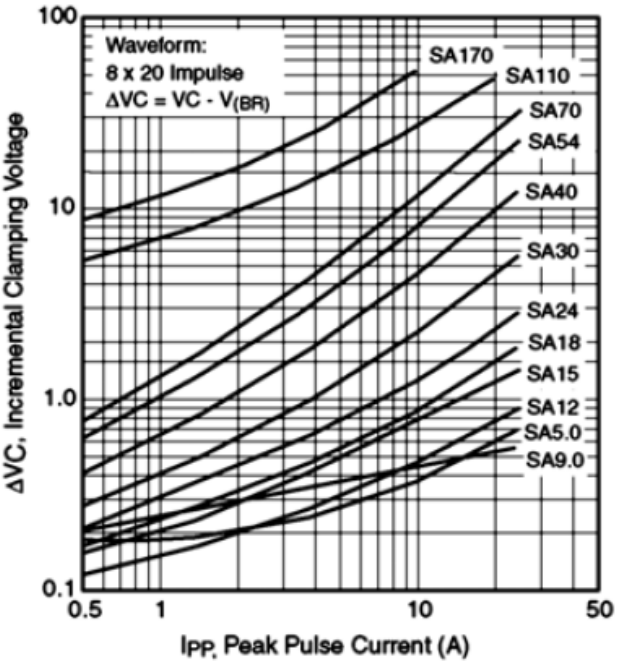


Fig. 8 – Incremental Clamping Voltage Curve Unidirectional

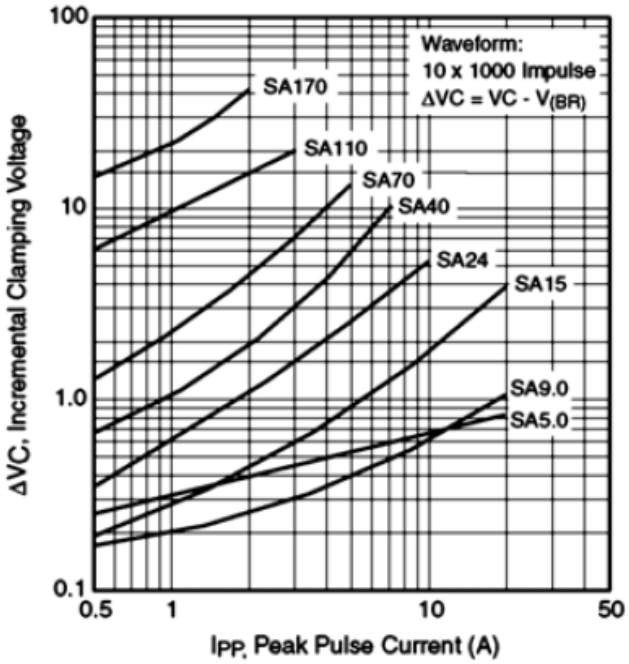


Fig. 9 – Incremental Clamping Voltage Curve Bidirectional

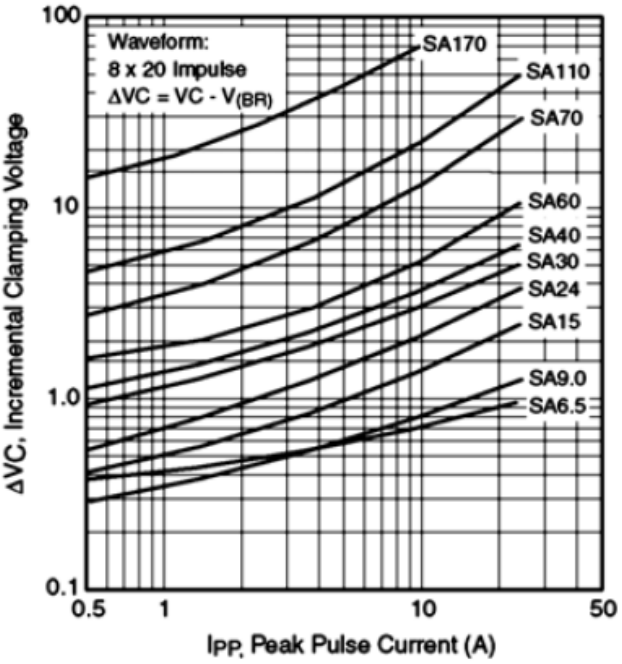
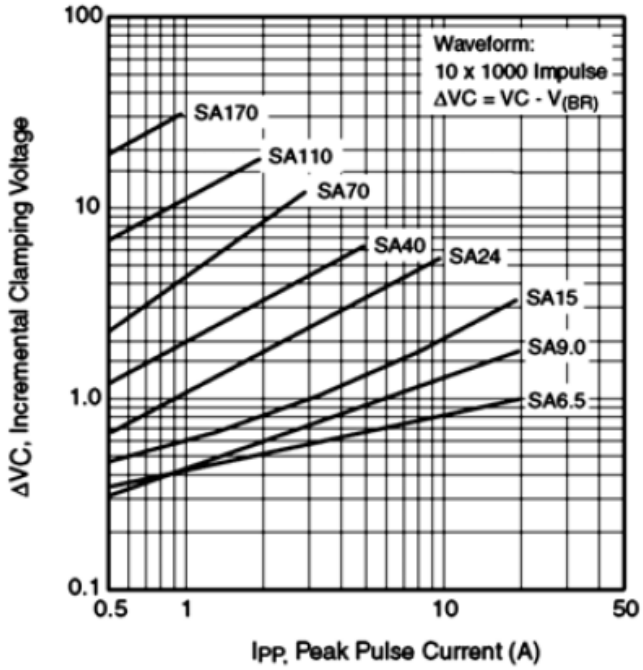


Fig. 10 – Incremental Clamping Voltage Curve Bidirectional



RATINGS AND CHARACTERISTIC CURVES (T_A = 25°C , unless otherwise specified.)

Fig. 11 – Typical Instantaneous Forward Voltage

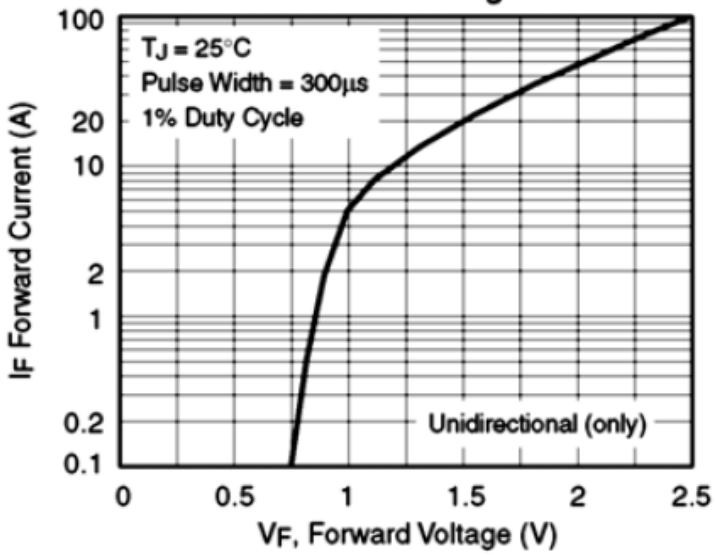
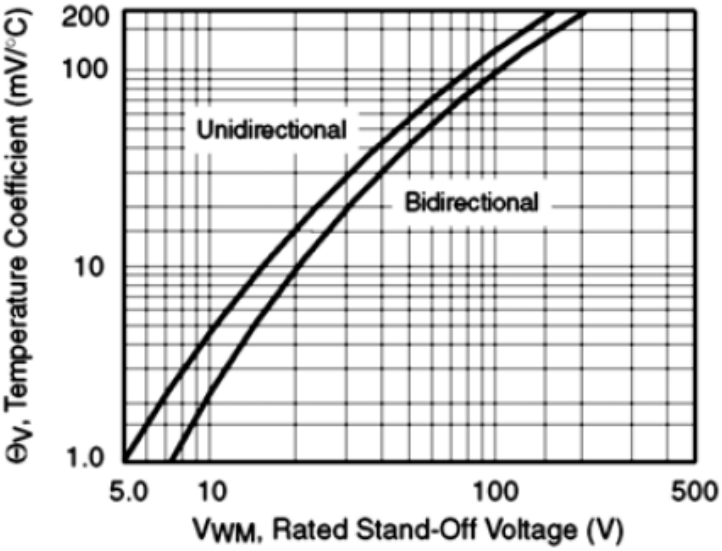


Fig. 12 – Breakdown Voltage Temperature Coefficient Curve



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